

### SANYO Semiconductors

# DATA SHEET

An ON Semiconductor Company

# 2SD1012 — Low-Voltage Large-Current Amplifier Applications

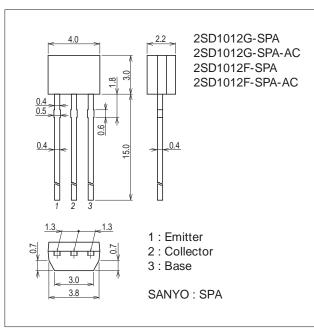
#### **Specifications**

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		20	V
Collector-to-Emitter Voltage	VCEO		15	V
Emitter-to-Base Voltage	VEBO		5	V
Collector Current	IC		0.7	Α
Collector Current (Pulse)	ICP		1.5	Α
Collector Dissipation	PC		250	mW
Junction Temperature	Tj		125	°C
Storage Temperature	Tstg		-55 to +125	°C

#### **Package Dimensions**

unit : mm (typ) 7524-004



#### **Product & Package Information**

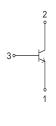
Package : SPAJEITA, JEDEC : SC-72

• Minimum Packing Quantity: 2,500 pcs./box, 500pcs./bag

#### Marking

# D1012

#### **Electrical Connection**



#### 2SD1012

#### **Electrical Characteristics** at Ta=25°C

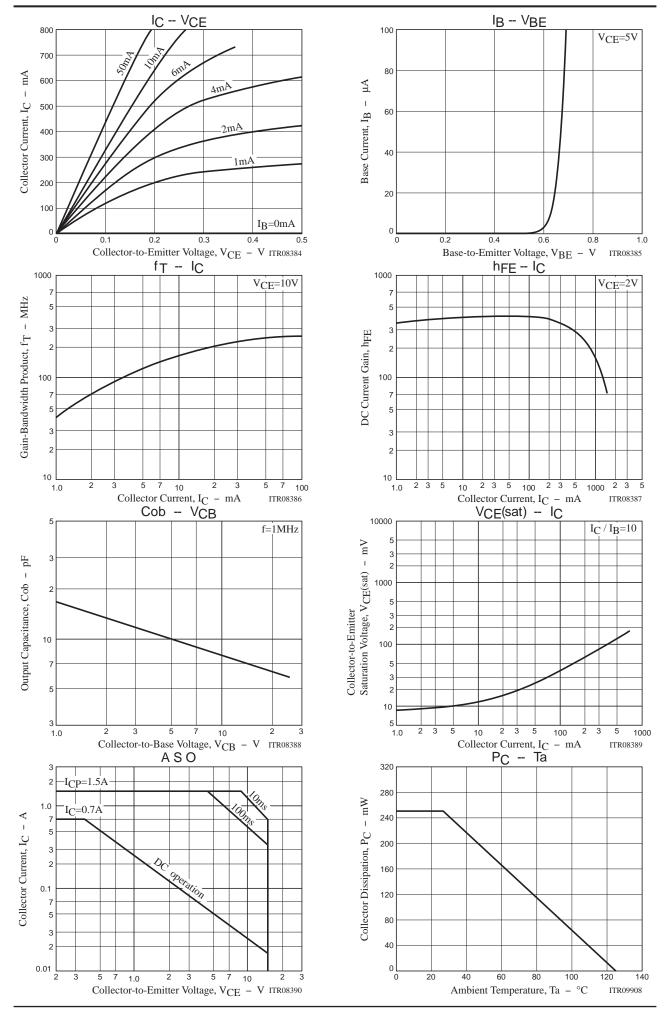
Parameter	Cumbal	Symbol Conditions		Ratings		
Farameter	Symbol		min	typ	max	Unit
Collector Cutoff Current	ICBO	V <sub>CB</sub> =15V, I <sub>E</sub> =0A			1.0	μΑ
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =4V, I <sub>C</sub> =0A			1.0	μΑ
DC Current Gain	hFE1	V <sub>CE</sub> =2V, I <sub>C</sub> =50mA	160*		960*	
DC Current Gain	hFE2	V <sub>CE</sub> =2V, I <sub>C</sub> =500mA Pulse	80			
Gain-Bandwidth Product	fT	VCE=10V, IC=50mA		250		MHz
Common Base Output Capacitance	Cob	V <sub>CB</sub> =10V, f=1MHz		8		pF
Collector-to-Emitter Saturation Voltage	V <sub>CE</sub> (sat)1	IC=5mA, IB=0.5mA		10	25	mV
Collector-to-Emitter Saturation voltage	V <sub>CE</sub> (sat)2	IC=100mA, IB=10mA		30	80	mV
Base-to-Emitter Saturation Voltage	VBE(sat)	IC=100mA, IB=10mA		0.8	1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=10μA, IE=0A	20			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=1mA, RBE=∞	15			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I <sub>E</sub> =10μA, I <sub>C</sub> =0A	5			V

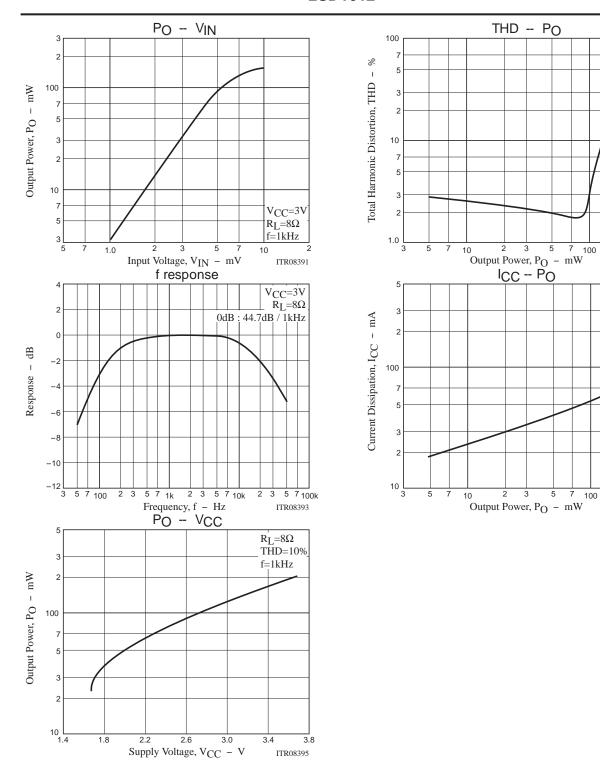
#### $\mbox{\ensuremath{^*}}$ : The 2SD1012 is classified by 50mA hFE as follows :

Rank	F	G	Н	
hFE	160 to 320	280 to 560	480 to 960	

#### **Ordering Information**

Device	Package	Shipping	memo
2SD1012G-SPA	SPA	500pcs./bag	
2SD1012G-SPA-AC	2G-SPA-AC SPA-WA		Db Free
2SD1012F-SPA	SPA	500pcs./bag	Pb Free
2SD1012F-SPA-AC	SPA-WA	2,500pcs./box	





 $V_{CC}=3V$   $R_L=8\Omega$  f=1kHz

ITR08392

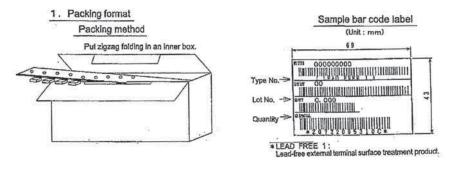
 $V_{CC}=3V$   $R_L=8\Omega$  f=1kHz

ITR08394

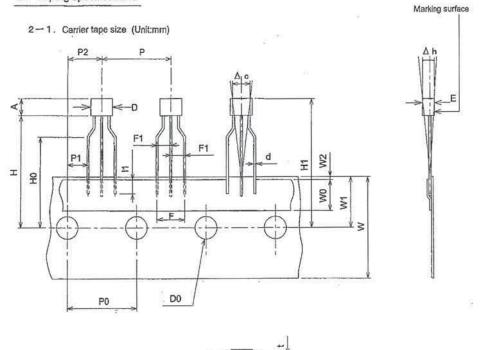
#### **Taping Specification**

2SD1012G-SPA-AC, 2SD1012F-SPA-AC

Storage package Package Outline name type	Package	Maximum Number of devices contained(pcs.)		Packing format		
	Inner box No.	Storage quantity	Outer box (C-6)	Outer box (C-8)		
	A C	C-2 Inner box Dimensions :mm(external) 330 × 45 × 145	2,500	16 inner boxes contained (40,000pcs.) Outer box Dimensions:mm(external) 5 8 5 × 3 4 5 × 2 0 0	8 inner boxes contained (20,000pcs. Outer box Dimensions:mm(external 3 4 5 × 3 0 0 × 2 0 0	
SPA AL	AL	C-2 Inner box Dimensions xmm(external) 330 × 45 × 145	2,400	16 inner boxes contained (38,400pcs.) Outer box Dimensions:mm(external) 5 8 5 × 3 4 5 × 2 0 0	8 inner boxes contained(19,200pcs.) Outer box Dimensions:mm(internal) 3 4 5 × 3 0 0 × 2 0 0	
	AP	C — 4 Inner box Dimensions :mm(external) 330 × 45 × 285	5,000	8 Inner boxes contained (40,000pcs.) Outer box Dimensions:mm(external) 5 8 5 × 3 4 5 × 2 0 0	4 inner boxes contained(20,000pcs.) Outer box Dimensions:mm(internal) 3 4 5 × 3 0 0 × 2 0 0	
	AS	C-2 Inner box Dimensions mm(external) 330 × 45 × 145	1,200	16 inner boxes contained(19,200 pcs.) Outer box Dimensions:mm(external) 5 8 5 × 3 4 5 × 2 0 0	8 inner boxes contained(9,600 pcs.) Outer box Dimensions:mm(intenal) 3 4 5 × 3 0 0 × 2 0 0	



#### 2. Taping specifications



#### 2-2. Taping size standard

Displacement of tape

ni		

Item	Symbol	Standard	Tolerance	Item
	D	4.0	±0.2	Tape width
Work piece outside diameter	E	2.2	±0.2	Adhesive tape
Work piece height	Α	3.0	±0.2	Displacement of perforations
Lead wire diameter	d	0.4×0.4 t	±0.1	Work piece bottom surface position
Bonded lead wire	11	2.5MIN		Lead wire clinch height
Pitch between products	Р	12.7	±1.0	Work piece upper limit position
Pitch between perforations	P0	12.7	±0.2	Perforations diameter
Total pitch for 21 perforations	P0×20	254.0	±1.0	Tape thickness (total thickness)
Distance between lead wire	F	5.0	+0.8	Product inclination
Lead wire pitch distance	F1	2.5	+0.4	
Product inclination	Δh	0	±2.0	
Dia-landari of a standari	P1	3.85	±0.3	To be measured at a position below the clinch
Displacement of perforations	P2	6.35	+03	

W2

0.5MAX

Item	Symbol	Standard	Tolerance
Tape width	w	18.0	+1.0 -0.5
Adhesive tape	wo	6.0	±1.0
Displacement of perforations	W1	9.0	+0.75
Work piece bottom surface position	Н	19.8	+1.0 -0.3
Lead wire clinch height	но	16.0	±0.5
Work piece upper limit position	H1	22.8	±1.5
Perforations diameter	D0	φ4.0	±0.2
Tape thickness (total thickness)	t	0.6	±0.2
Product inclination	Δο	0	±1.0

2—3. Taping structure

Marking surface

Thermo-compression tape

Board

Empty section

Inserted section

Empty section

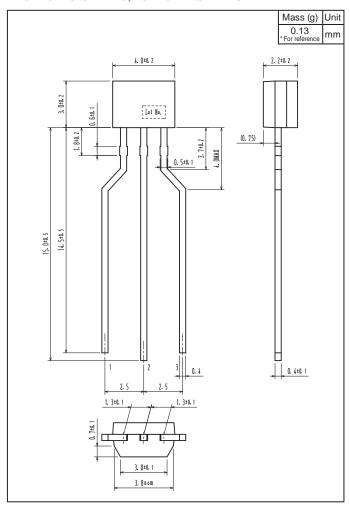
Not to be displaced to the outside of the board

- · Provide an empty section for about three to five pieces in leading and end portions of the tape.
- Marked in red

· Provide marking in red to the E-side end of the board.

#### **Outline Drawing**

2SD1012G-SPA-AC, 2SD1012F-SPA-AC



#### **Bag Packing Specification**

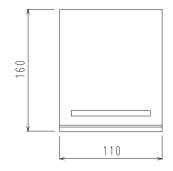
#### 2SD1012G-SPA, 2SD1012F-SPA

#### 1. Packing Format

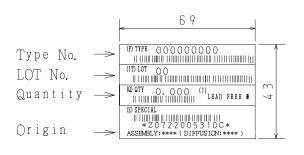
Package Name		Maximum Number of devices contained (pcs)				
	Вад	Inner	ВОХ	Outer BOX		
Q.D.I.		B-1	B-1/2	A-1	A-2	
SPA   500	20,000 10,000		100,000	60,000		
Packing format (Din				ensions:mm (ext	ernal))	
		Inner BOX		Outer	ВОХ	
	B-1		B-1/2	A-1	A-2	
	445×225×55		445×225×55	470×250×300	470×250×190	

## 2. Bag dimensions

(unit:mm)

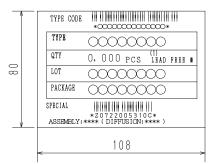


#### 3. Bag label, Inner box label (unit:mm)



#### 4. Outer box label (unit:mm)

It is a label at the time of factory shipments. The form of a label may change in physical distribution process.



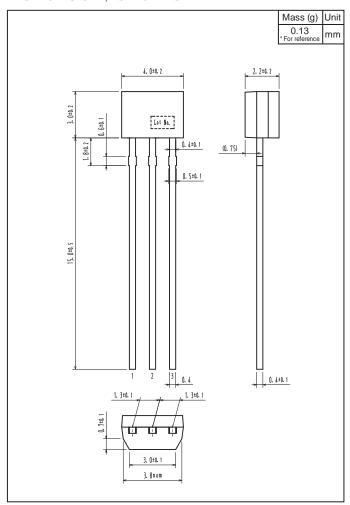
#### NOTE (1)

The LEAD FREE \* description shows that the surface treatment of the terminal is lead free.

Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

#### **Outline Drawing**

2SD1012G-SPA, 2SD1012F-SPA



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